

## Damper diode

BY428

### FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

### APPLICATIONS

- Damper diode in high frequency horizontal deflection circuits up to 64 kHz.

### DESCRIPTION

Rugged glass package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

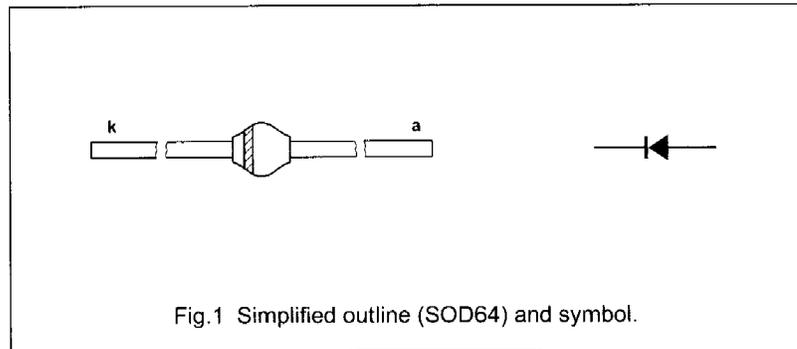


Fig.1 Simplified outline (SOD64) and symbol.

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

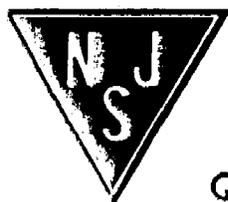
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RSM}$	non-repetitive peak reverse voltage		–	1500	V
$V_{RRM}$	repetitive peak reverse voltage		–	1500	V
$V_R$	continuous reverse voltage		–	1400	V
$I_{FWM}$	working peak forward current	$T_{ip} = 80^\circ\text{C}$ ; lead length = 10 mm; see Fig.2	–	4	A
$I_{FRM}$	repetitive peak forward current		–	8	A
$I_{FSM}$	non-repetitive peak forward current	$t = 10$ ms half sinewave; $T_j = T_{jmax}$ prior to surge; $V_R = V_{RRMmax}$	–	50	A
$T_{stg}$	storage temperature		–65	+175	$^\circ\text{C}$
$T_j$	junction temperature		–65	+150	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS

$T_j = 25^\circ\text{C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
$V_F$	forward voltage	$I_F = 4$ A; $T_j = T_{jmax}$ ; see Fig.3	1.60	V
		$I_F = 4$ A; see Fig.3	1.95	V
$I_R$	reverse current	$V_R = V_{Rmax}$ ; $T_j = 150^\circ\text{C}$	150	$\mu\text{A}$
$t_{rr}$	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.6	250	ns
$t_{fr}$	forward recovery time	when switched to $I_F = 5$ A in 50 ns; $T_j = T_{jmax}$ ; see Fig.7	250	ns

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**THERMAL CHARACTERISTICS**

<b>SYMBOL</b>	<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>VALUE</b>	<b>UNIT</b>
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	75	K/W
		mounted as shown in Fig.5	40	K/W